

IRLML6346TRPBF

IRLML6346TRPBF Information



Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



IRLML6346TRPBF Specifications

Manufacturer Part Number	IRLML6346TRPBF
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-236-3, SC-59, SOT-23-3
Series	HEXFET?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	30V
Current - Continuous Drain (Id) @ 25°C	3.4A (Ta)
Drive Voltage (Max Rds On, Min Rds On)	2.5V, 4.5V
Vgs(th) (Max) @ Id	1.1V @ 10µA
Gate Charge (Qg) (Max) @ Vgs	2.9nC @ 4.5V
Input Capacitance (Ciss) (Max) @ Vds	270pF @ 24V
Vgs (Max)	±12V
FET Feature	-
Power Dissipation (Max)	1.3W (Ta)
Rds On (Max) @ Id, Vgs	63 mOhm @ 3.4A, 4.5V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	Micro3?/SOT-23
Package / Case	TO-236-3, SC-59, SOT-23-3
	Report errors?

IRLML6346TRPBF Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

IRLML6346TRPBF Payment Methods



IRLML6346TRPBF Shipping Methods



If you have any question about IRLML6346TRPBF, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com